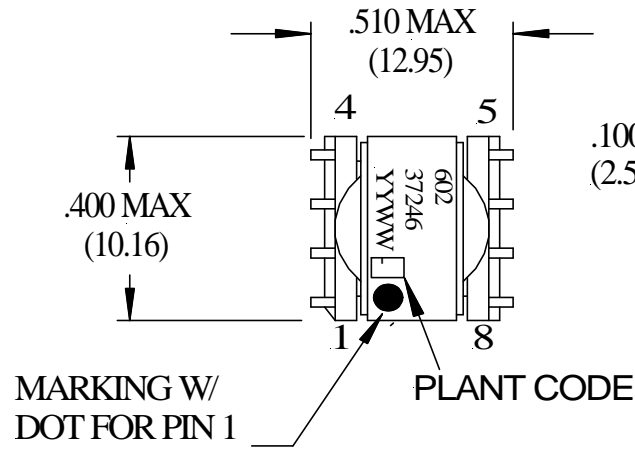


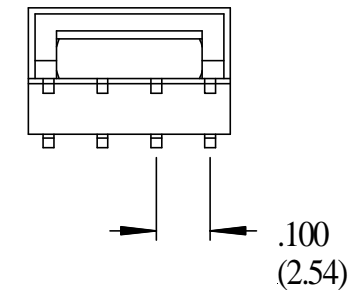
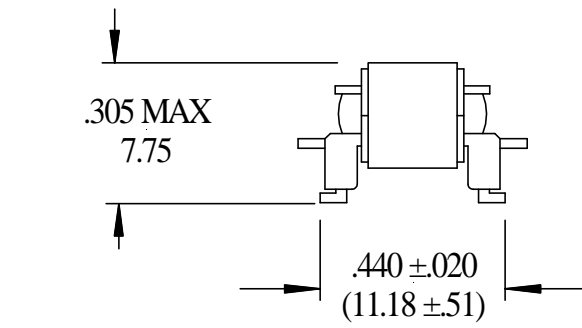
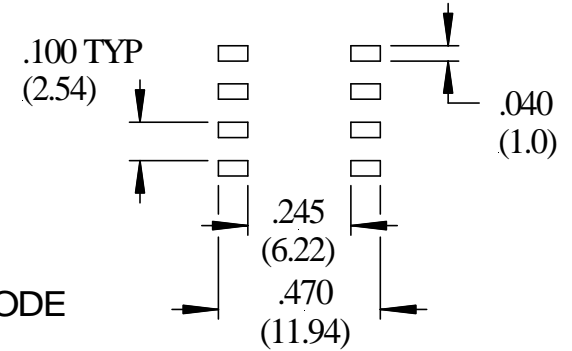
SPECIFICATIONS:

1. TEMP CLASS 130°C
2. INDUCTANCE: @ 0.1 Vrms, 10 KHz
1-4 = 225 μHy MIN
3. LEAKAGE INDUCTANCE: @ 100 KHz, 1-4
WITH 5-8 SHORTED = 0.7 μHy MAX
4. IWC: @ 100 KHz, 1-4 TO 5-8 WITH
SHIELD GROUNDED = 2 pF MAX
5. TURNS RATIO: 1-4 : 5-8 = 1 : 1 ± 2%
6. DC RESISTANCE: 1-4, 5-8 = 0.10 OHMS NOM
7. DIELECTRIC STRENGTH: 1500 Vac

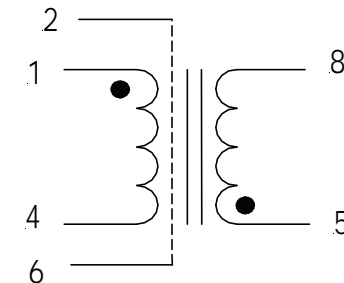
Designed to operate with Crystal Semiconductor
CS8401, 8402, 8411, & 8412



**RECOMMENDED
PAD LAYOUT**



NOTE:
COPLANARITY < .006 (0.15)



| | | | | |
|---------------------------------------|------------------|--------------|----------------|-------------|
| TOLERANCES UNLESS OTHERWISE SPECIFIED | INCHES / DECIMAL | .XX = ± .01 | .XXX = ± 0.010 | ANGLES ± 1° |
| | MILLIMETERS (mm) | .XX = ± 0.20 | | |